A chieving fast oxygen di usion in perovskites by cation ordering

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The oxygen-exchange behavior has been studied in half-doped manganese and cobalt perovskite oxides. We have found that the oxygen di usivity in $Gd_{9:5}Ba_{0:5}MnO_3$ can be enhanced by orders of magnitude by inducing crystallographic ordering among lanthanide and alkali-earth ions in the A-site sublattice. Transform ation of a simple cubic perovskite, with random ly occupied A-sites, into a layered crystalG dB aM n_2O_{5+x} (or isostructuralG dB aC o_2O_{5+x} for cobalt oxide) with alternating lanthanide and alkali-earth planes reduces the oxygen bonding strength and provides disorder-free channels for ion motion, pointing to an elected way to design new ionic conductors.

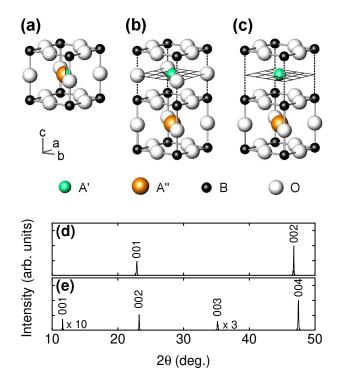
PACS num bers: 66.30 H s, 82.47 E d

O xygen ion conductors - solids exhibiting very fast oxygen di usion - constitute the basis for such emerging technologies as the membrane oxygen separation or the solid-oxide fuel cell (SOFC) power generation.^{1,2}. These technologies o er enorm ous econom ical and ecological bene ts provided high perform ance materials can be developed: The scienti c challenge is to design materials dem onstrating high oxygen di usivity at low enough tem perature.

In general, a crystal must meet two fundamental requirements to be a good oxygen-ion conductor: (i) it must contain a lot of vacancies in the oxygen sublattice, and (ii) the energy barrier for oxygen migration from one site to another must be fairly small, typically less than 1 eV. Only a few types of oxides, and perovskites ABO₃ (A is a rare-earth or an alkali-earth element and B is typically a transition m etal) among them , have been found to possess these features.^{1,2,3,4,5,6,7,8} D oped perovskites, which possess a high electronic conductivity in addition to the ionic one, are considered for using as electrodes in SOFC and as oxygen-selective m em branes; for example, strontium -doped lanthanum m anganese oxide, $La_{1 v} Sr_v M nO_3$, is a standard cathode material for SOFC applications operating at tem peratures around 1000 C.⁶ Recently, serious e orts are made to reduce the operation tem perature of SOFC, and for the operation at 700 - 800 C, strontium -doped lanthanum cobalt oxide, $La_{1} \times Sr_{v}CoO_{3}$, is considered to be the most prom ising cathode m aterial.^{7,8} The perform ance of perovskite oxides has been already optimized as much as possible mostly by means of various ion substitutions in both A and B sublattices,^{6,7,8,9} but they still fail to operate at low enough tem peratures 500 C required for successful com m ercialization of the fuel cell technology.

In this Letter, we show that the oxygen-ion di usion in a doped perovskite can be enhanced by orders of magnitude if a simple cubic crystal [schematically shown in Fig.1 (a)] transforms into a layered compound with ordered lanthanide and alkali-earth ions [Fig. 1 (b)], which reduces the oxygen bonding strength and provides disorder-free channels for ion motion.

Recently, the A-site-ordered manganese and cobalt perovskite oxides have been synthesized by several



F IG. 1: O rdering of lanthanide $A^{r^{3+}}$ and alkali-earth $A^{r^{2+}}$ ions in the A-site sublattice of half-doped perovskites. (a) A simple cubic perovskite $A'_{0:5}A^{"}_{0:5}BO_3$ with random occupation of A-sites is transformed into (b) a layered crystal A 'A "B₂O₆ by doubling the unit cell, provided the di erence in ionic radiiof A' and A" ions is su ciently large. (c) O xygen atom s can be partially or com pletely rem oved from lanthanide planes in A'A "B₂O_{5+x}, providing a variability of the oxygen content, 0 x 1. (d, e) X-ray Bragg's (00L) peaks obtained for cubic G d_{0.5}B a_{0.5}M nO₃ (d) and layered G dB aM n₂O_{5+x} (e), which dem onstrate the doubling of the unit cell along the c axis with the cation ordering (for convenience, the peak intensity is multiplied by a factor indicated near each peak).

groups.^{10,11} W e have succeeded in growing high-quality single crystals of these compounds by the oatingzone (FZ) technique.¹² W hat makes these layered oxides promising for searching a high oxygen mobility is their remarkable variability of oxygen content: 0 xygen atom s can be partially or even completely removed from the lanthanide planes [as shown in Fig. 1 (c)], creating a lot of vacant sites in the crystal lattice. W hile polycrystalline air-sintered sam ples of G dB aM n_2O_{5+x} adopt the cubic perovskite crystal structure (and thus should be expressed as G d_{0.5}B a_{0.5}M nO₃), the ordered phase can be grown under strongly reducing atm osphere of pure argon. The fortunate opportunity to obtain both layered G dB aM n_2O_{5+x} and cubic G d_{0.5}B a_{0.5}M nO₃ phases allows direct comparison of the oxygen behaviour in materials with and without the A-site sublattice ordering. For the cobalt oxide, on the other hand, only the ordered G dB aC o_2O_{5+x} phase can be obtained even at high oxygen pressure.

The hom ogeneity and cation stoichiom etry of our crystals are con med by the electron-probe microanalysis (EPM A) and the inductively-coupled plasm a (ICP) spectroscopy. Ordering of the Gd and Ba ions into consecutive (001) layers is con med by the X-ray di raction measurements [Fig. 1(d) and (e)], which clearly dem onstrate the doubling of the unit cell along the c axis for $G dB aM n_2 O_{5+x}$ single crystals. The behaviour of dc resistivity shows that both $G dB a M n_2 O_{5+x}$ and G dB aC 020 5+ x undergo an insulator-to-m etal transition upon increasing tem perature; at high tem peratures, they possess a m etallic conductivity of the order of 10^2 and 10^3 S/cm, respectively. These values are much larger than any ionic conductivity available in solids, indicating that these compounds should be mixed ionic and electronic conductors (M ECs).

It is well known that in M ECs, the ionic conductivi, which is typically much smaller than the elec-İtу tronic conductivity e, may be determined from di usion measurements.^{13,14} In oxides with variable oxygen stoichiom etry, like G dB aM n_2O_{5+x} and G dB aC o_2O_{5+x} , a sharp change in conditions (oxygen pressure or tem perature) results in a gradual transition into a new equilibrium state that di ers in oxygen content; this m eans that the oxygen concentration in crystal sam ples changes with time, which can be measured as a weight change. The observed relaxation time depends on two processes: the oxygen exchange at the interface between the gas and the solid, and the oxygen bulk di usion. In the present study, both the surface exchange coe cient K and the chemicaldi usion coe cient D are obtained by examining the weight change of crystals as a function of time.

The oxygen-exchange behaviour in cubic manganese oxide and its layered counterpart, studied in polycrystalline samples with comparable morphology, is shown in Fig. 2. There are two clear consequences of the A-site ordering: First, as shown in Fig. 2(a), the change in the equilibrium oxygen content x_{eq} upon decreasing oxygen pressure from 1 to 10⁵ bar at 700 C is much more pronounced in the layered oxide. Thus, it is much easier to remove oxygen from the layered G dB aM n_2O_{5+x} than from cubic G $d_{0:5}Ba_{0:5}M nO_3$. Second, and more important, is a huge di erence in the rate of the oxygen content $x_{norm} = (x x_0) = (x_{eq} x_0) (x_0 is the initial oxygen)$

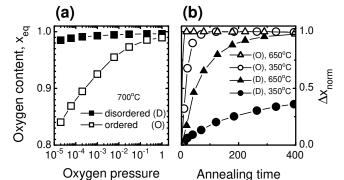
content and x_{eq} is the equilibrium one), m easured during the annealing in the oxygen gas ow at 350 C and 650 C, for sam ples w ith ordered (open sym bols) and disordered (lled sym bols) A -site sublattice. The relaxation time is about two orders of m agnitude sm aller in the layered oxide. Surprisingly, the oxygen accumulation in the layered G dB aM n_2O_{5+x} even at 350 C turns out to be faster than that in the cubic G d_{0.5}B a_{0.5}M nO₃ at 650 C.

Having established that the ordering of the A-site sublattice into a layered structure signi cantly enhances the oxygen relaxation rate, we now turn to a more quantitative analysis of the oxygen di usion. For that purpose, how ever, large single-crystal samples of G dB aM n_2O_{5+x} appear to be unsuitable; depending on x, the orthorhom bicity (b a)=a in G dB a M n_2O_{5+x} varies from 0 up to 7%, and the enorm ous strains em erging upon the oxygen intercalation into large single crystals result in the form ation of a regular array of cracks on the crystal surface. We therefore focus our quantitative analysis on another layered material G dB aC $o_2 O_{5+x}$, which does not have such a problem . To separate the surface-exchange and bulkdi usion contributions to the overall oxygen exchange rate, we study the oxygen kinetics in G dB aC o₂O _{5+ x} single crystals of di erent size: the oxygen kinetics is mostly lim ited by the surface exchange for sm all-size crystals, while for large-size crystals it is mostly limited by the bulk di usion. The change in weight with time in a rectangular-shape sam ple of a given size has an analytical solution,¹⁴ which is a function of both the chem ical diffusion coe cient D and the surface exchange coe cient K. Figure 3 shows the experim ental data (symbols) and analytical ts (solid lines) of the change in the oxygen content with time for G dB aC o₂O _{5+ x} single-crystal sam ples of di erent sizes upon annealing in the oxygen ow at 350 C. From this set of data, the parameters D and

FIG. 2: Comparison of oxygen behaviour in cubic $Gd_{0:5}Ba_{0:5}MnO_3$ with disordered A-site sublattice (i.e. random ly distributed Gd^{3+} and Ba^{2+} ions) and layered $GdBaMn_2O_{5+x}$. (a) Equilibrium oxygen content x_{eq} (for $Gd_{0:5}Ba_{0:5}MnO_3$, x=1-2) measured at 700 C as a function of the oxygen partial pressure. (b) Norm alized change in the oxygen content with time during annealing in the oxygen gas ow at 350 C and 650 C.

(min)

(bar)



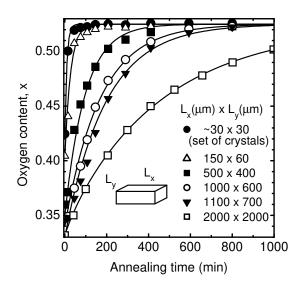


FIG. 3: Time dependence of the oxygen content in rectangular-shaped G dB aC o_2O_{5+x} single crystals of di erent sizes while annealing in the oxygen ow at 350 C (symbols). Solid lines represent theoretical curves with a unique pair of parameters $D = 3 \ 10^7 \ \text{cm}^2/\text{s}$ and $K = 2 \ 10^6 \ \text{cm}/\text{s}$ for the whole set of experimental data.

K can be uniquely determ ined to be $D = 3 \ 10^7 \ cm^2/s$ and $K = 2 \ 10^6 \ cm/s$. We note that the oxygen kinetics does not show any detectable di erence upon varying the sample size along the c axis in the range of 30-500 m, im plying an essentially two-dimensional character of the oxygen di usion in this layered material.

Using the technique described above, we have determ ined the parameters D and K for the tem perature range of 250-600 C at 1 bar oxygen pressure Fig. 4(a)]. These data are well tted by the activation laws $D (\text{cm}^2 = \text{s}) = 0:15$ exp(0.7 eV = kT) and K (cm/s) = $\exp(0.85 \text{ eV} = \text{kT})$, revealing quite low activation 15 energies for both processes. As a result, the oxygen diffusion in $G dB aC o_2 O_{5+x}$ becomes very fast already at rather low tem peratures, exceeding 10 $^5\,$ cm $^2/s$ at 600 C . To appreciate the true merit of this high oxygen di usivity in $G dB a C o_2 O_{5+x}$, it is worth estimating the ionic conductivity, which is uniquely determined by the selfdi usion (ortrace-di usion) coe cient D.¹⁵ O ne should keep in m ind that the chem ical di usion coe cient D, obtained in our experiments, is related to D through a so-called therm odynam ic factor $[(@ \ln P = 0 \ln x) = 2],$ D = D, re ecting the fact that the true driving force for di usion is a gradient in the chemical potential but not a gradient in the oxygen concentration.¹⁵ In $G dB aC o_2 O_{5+x}$, turns out to be quite low and does

not exceed 10 in the whole tem perature and oxygenpressure range studied [Fig. 4 (b)]. Thus, the ionic conductivity of 0.01 S/cm, which is considered as a criterion for SOFCs to be valuable¹, can be achieved in G dB aC o_2O_{5+x} already at 500 C.C learly, there should still be a possibility for further in provem ent of properties in ordered perovskite oxides, and the most obvious way is a substitution of di erent rare earths for G d.

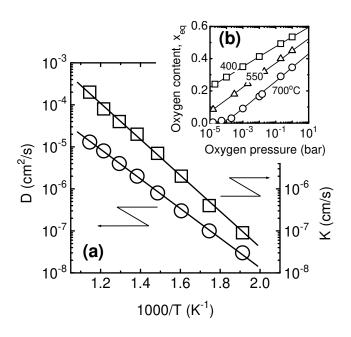


FIG.4: O xygen bulk di usion and surface oxygen exchange in G dB aC $_{2}O_{5+x}$. (a) Tem perature dependences of the diffusion coe cient D (T) and the surface exchange coe cient K (T), obtained from the oxygen kinetics experiments similar to those shown in Fig.3. The inset (b) shows the dependence of the equilibrium oxygen content x_{eq} on the oxygen pressure P for several tem peratures.

In conclusion, we have found a remarkable enhancement of the oxygen di usivity in ordered perovskite oxides as exemplied in GdBaM n_2O_{5+x} and GdBaC o_2O_{5+x} , which opens a possibility to develop a new class of materials suitable for applications that require a fast oxygen transport in the intermediate tem – perature range. The improvement of the oxygen transport properties induced by the cation ordering in halfdoped perovskites provides a good example of how the formation of a layered crystal structure, with disorderfree channels for ions migration and with a weakened bonding strength of oxygen, can signi cantly facilitate the oxygen motion in the crystal lattice.

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